

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	40940	(monolayer or mono-layer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/10 12:06
S2	1051	S1 with (barrier or (etching adj stop) or etch adj stop)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/30 10:58
S3	25	S2 with substrate and gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/30 10:58
S4	139823	(monolayer or mono-layer or single-layer or (single adj layer))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/30 10:58
S5	3214	S4 with (barrier or (etching adj stop) or etch adj stop)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/30 10:58
S6	79	S5 with substrate and gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/30 10:58
S7	2112	(source or drain) with (sige or (silicon adj germanium) or ("si. sub?Ge. sub?")))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/10 15:13
S8	75	(monolayer or mono-layer or (mono adj layer)) and S7	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/10 12:09
S9	3553	(257/19,368,369,382).CCLS.	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/10 13:41
S10	3515	S9 and (@ad<"20040730" or @rlad<"20040730")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/10 13:42

S11	2498	S10 and substrate and (source or drain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/10 13:43
S12	139	S11 and strain\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/10 15:03
S13	16	(monolayer or mono-layer) and S11	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/10 15:03

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	787	(source or drain) with (sige or (silicon adj germanium) or ("si. sub?Ge. sub?"))	US-PGPUB	OR	ON	2006/02/10 15:14
L2	43	I1 and (monolayer or mono-layer)	US-PGPUB	OR	ON	2006/02/10 15:14